

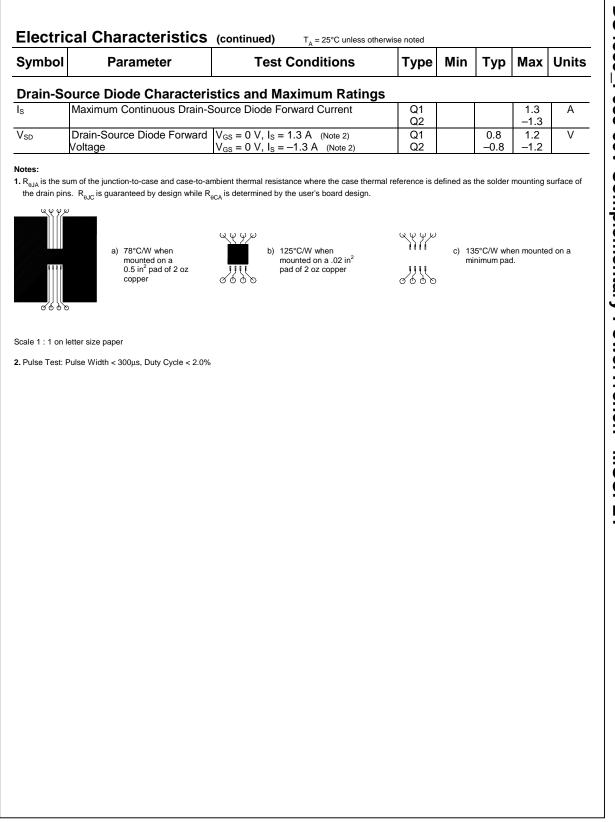
Package Marking and Ordering informationDevice MarkingDeviceReel SizeTape widthQuantityFDS4559FDS4559_F08513"12mm2500 units

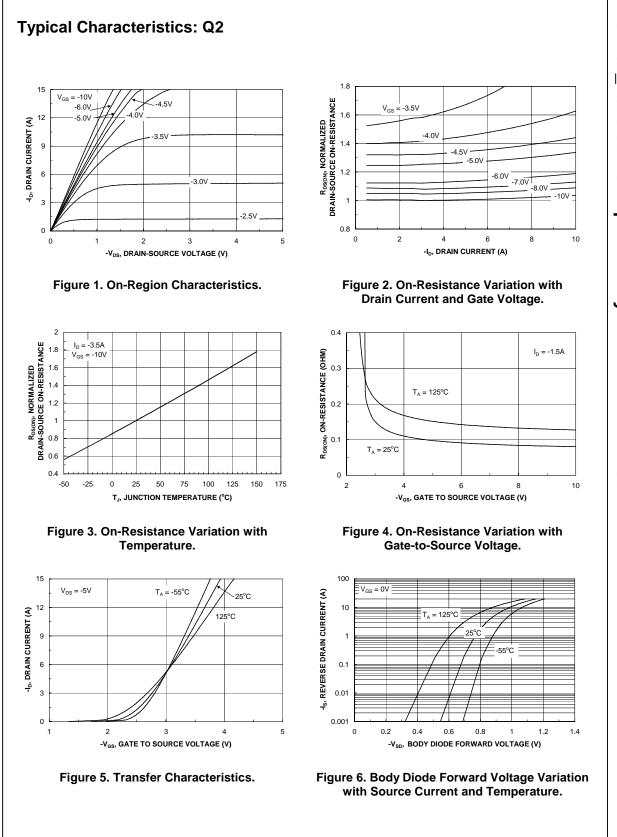
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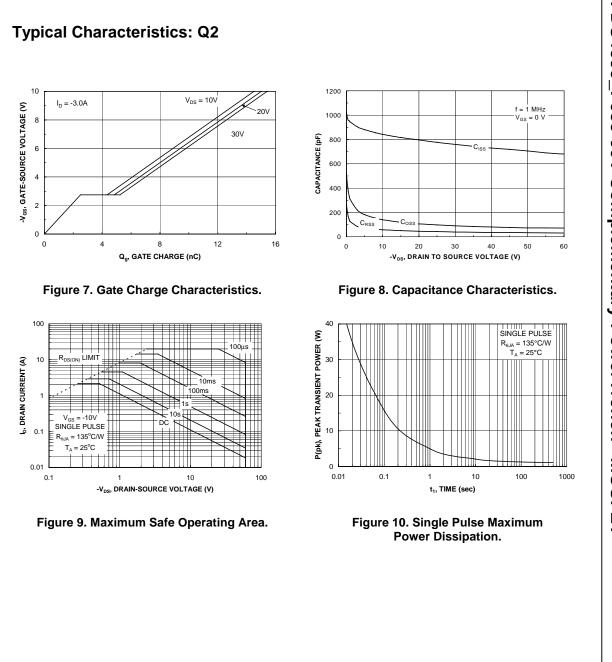
Symbol	Parameter	Test Conditions	Туре	Min	Тур	Max	Units
Drain-So	ource Avalanche Ratin	QS (Note 1)					
W _{DSS}	Single Pulse Drain-Source Avalanche Energy	$V_{DD} = 30 \text{ V}, \qquad I_D = 4.5 \text{ A}$	Q1			90	mJ
I _{AR}	Maximum Drain-Source Avalanche Current		Q1			4.5	A
Off Cha	racteristics						
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 V, I_D = 250 \mu A$ $V_{GS} = 0 V, I_D = -250 \mu A$	Q1 Q2	60 60			V
$\Delta BV_{DSS} \Delta T_{J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, Referenced to 25°C $I_D = -250 \ \mu$ A, Referenced to 25°C	Q1 Q2		58 49		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 48 \text{ V}, V_{GS} = 0 \text{ V}$ $V_{DS} = -48 \text{ V}, V_{GS} = 0 \text{ V}$	Q1 Q2			1 _1	μA
I _{GSS}	Gate-Body Leakage	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$ $V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	Q1 Q2			<u>+</u> 100 +100	nA
On Cha	racteristics (Note 2)		~-			<u></u>	
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$ $V_{DS} = V_{GS}, I_D = -250 \ \mu A$	Q1 Q2	1 –1	2.2 -1.6	3 -3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, Referenced to 25°C $I_D = -250 \ \mu$ A, Referenced to 25°C	Q1 Q2		-5.5 4		mV/°C
R _{DS(on)}	Static Drain-Source On-Resistance	$V_{GS} = 10 \text{ V}, I_D = 4.5 \text{ A}$ $V_{GS} = 10 \text{ V}, I_D = 4.5 \text{ A}$ $V_{GS} = 10 \text{ V}, I_D = 4.5 \text{ A}, T_J = 125^{\circ}\text{C}$ $V_{GS} = 4.5 \text{ V}, I_D = 4 \text{ A}$	Q1		42 72 55	55 94 75	mΩ
			Q2		82 130 105	105 190 135	
I _{D(on)}	On-State Drain Current	$V_{GS} = 10 \text{ V}, V_{DS} = 5 \text{ V}$ $V_{GS} = -10 \text{ V}, V_{DS} = -5 \text{ V}$	Q1 Q2	20 20			A
g _{FS}	Forward Transconductance	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 4.5 \text{ A}$ $V_{DS} = -5 \text{ V}, \text{ I}_{D} = -3 5 \text{ A}$	Q1 Q2		14 9		S
Dynami	c Characteristics						4
C _{iss}	Input Capacitance	Q1 $V_{DS} = 25 V, V_{GS} = 0 V,$	Q1 Q2		650 759		pF
C _{oss}	Output Capacitance	f = 1.0 MHz	Q1 Q2		80 90		pF
C _{rss}	Reverse Transfer Capacitance	$V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1.0 MHz	Q1 Q2		35 39		pF
							.1
	g Characteristics (Note :				<u> </u>		T
l(on)	Turn-On Delay Time	Q1 V _{DD} = 30 V, I _D = 1 A,	Q1 Q2		11 7	20 14	ns
	Turn-On Rise Time	$V_{GS} = 10V, R_{GEN} = 6 \Omega$	Q1 Q2		8 10	18 20	ns
d(off)	Turn-Off Delay Time	Q2 V _{DD} = -30 V, I _D = -1 A,	Q1 Q2		19 19	35 34	ns
	Turn-Off Fall Time	$V_{GS} = -10$ V, $R_{GEN} = 6$ Ω	Q1 Q2		6 12	15 22	ns
) ^a	Total Gate Charge	Q1 V _{DS} = 30 V, I _D = 4.5 A, V _{GS} = 10 V	Q1 Q2		12.5 15	18 21	nC
Q _{gs}	Gate-Source Charge	Q2	Q1 Q2		2.4 2.5		nC
Q _{gd}	Gate-Drain Charge	$V_{DS} = -30 \text{ V}, \text{ I}_{D} = -3.5 \text{ A}, \text{ V}_{GS} = -10 \text{ V}$	Q1 Q2		2.6 3.0		nC

FDS4559_F085 60V Complementary PowerTrench[®] MOSFET

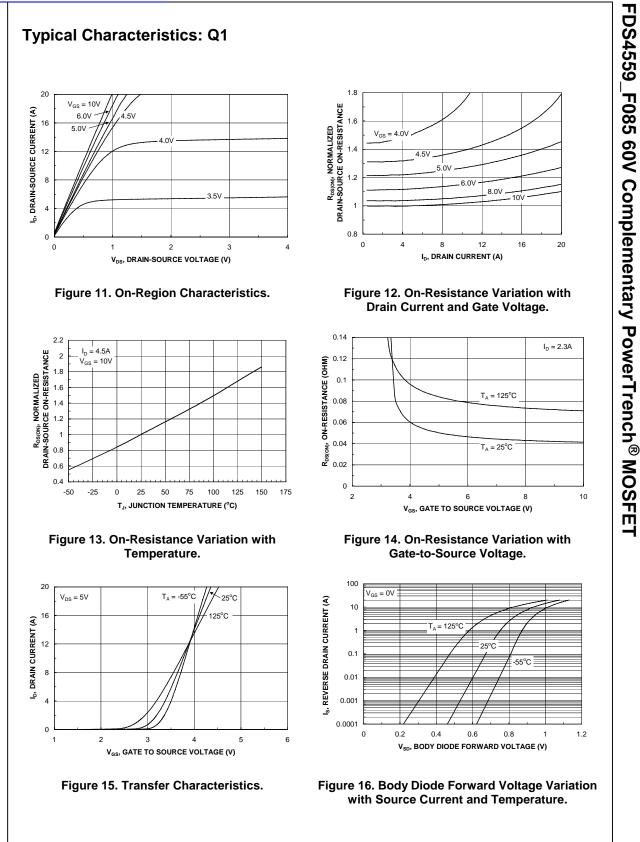




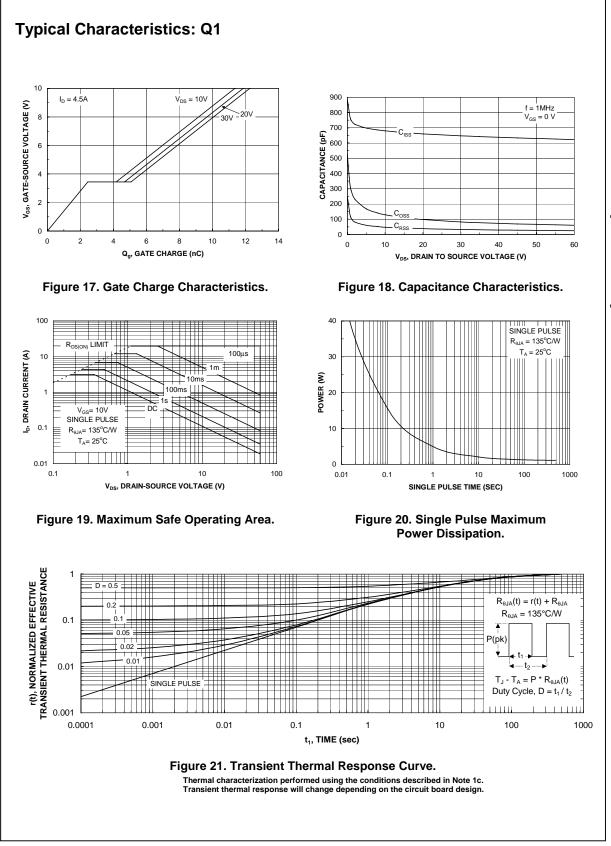
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